



DMG3402L

N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	I _D T _A = +25°C
	52mΩ @ V _{GS} = 10V	4A
30V	65mΩ @ V _{GS} = 4.5V	3A
	$85m\Omega @ V_{GS} = 2.5V$	2A

Features

- Low On-Resistance:
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Applications

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays

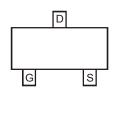
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

SOT23







Pin Configuration

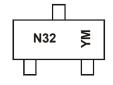
Ordering Information (Note 4)

Part Number	Case	Packaging
DMG3402L-7	SOT23	3000/Tape & Reel
DMG3402L-13	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://:www.diodes.com/products/packages.html.

Marking Information



N32 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

Date Code Key

Year	2012	2	2013		2014	20	15	2016		2017		2018
Code	Z		Α		В	(\sim	D		E		F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V_{DSS}	30	V
Gate-Source Voltage	V_{GSS}	±12	V
Drain Current (Note 5)	I _D	4.0	Α
Body-Diode Continuous Current (Note 5)	Is	1.5	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	1.4	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	$R_{\theta JA}$	90	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)					•		
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Body Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)			•	•		•	
Gate Threshold Voltage	V _{GS(th)}	0.6	_	1.4	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
			_	52		$V_{GS} = 10V, I_D = 4A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		_	65	mΩ	$V_{GS} = 4.5V, I_D = 3A$	
			_	85		$V_{GS} = 2.5V, I_D = 2A$	
Forward Transconductance	Y _{fs}	_	6.6		S	$V_{DS} = 5V, I_{D} = 3.1A$	
Source-Drain Diode Forward Voltage	V _{SD}		_	1.16	V	$V_{GS} = 0V, I_S = 2.0A$	
DYNAMIC CHARACTERISTICS(Note 7)							
Gate Resistance	R_g	_	2.2	_	Ω	V_{DS} =0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (10V)	Qg	_	11.7	_	nC	$V_{GS} = 10 \text{ V}, V_{DS} = 15 \text{V},$ $I_D = 4 \text{ A}$	
Total Gate Charge (4.5V)	Qa	_	5.5	_	nC	., ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	
Gate-Source Charge	Q_{gs}	_	1.1	_	nC	$V_{GS} = 10 \text{ V}, V_{DS} = 15 \text{ V},$	
Gate-Drain Charge	Q_gd	_	1.8	_	nC	I _D = 4 A	
Turn-On Delay Time	$t_{D(on)}$	_	1.9	_	ns		
Turn-On Rise Time	t _r	_	1.6	_	ns	V _{DD} = 15V, V _{GEN} = 10V,	
Turn-Off Delay Time	t _{D(off)}	_	10.3	_	ns	$R_{GEN} = 3\Omega$, $R_L = 3.75\Omega$	
Turn-Off Fall Time	t _f	_	2.0	_	ns		
Input Capacitance	C _{iss}	_	464	_	pF		
Output Capacitance	Coss	_	49.5	_	pF	V _{DS} = 15V, V _{GS} = 0V - f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	43.8	_	pF	TI = I.UIVIMZ	

Notes:

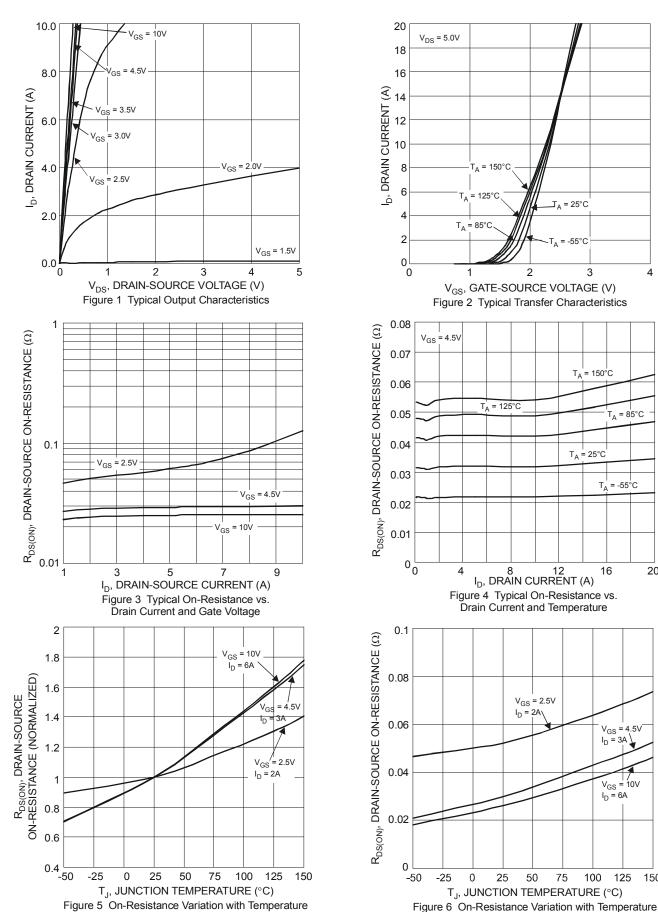
- 5. Device mounted on FR-4 PCB. t ≤5 sec.
- 6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to production testing.

T_A = 85°C

 $T_{A}' = -55^{\circ}C$

20





150

 $V_{GS} = 10V$ $I_{D} = 6A$

125



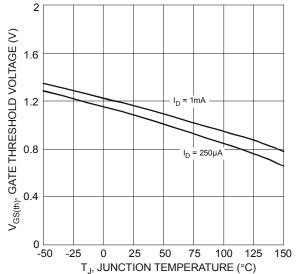
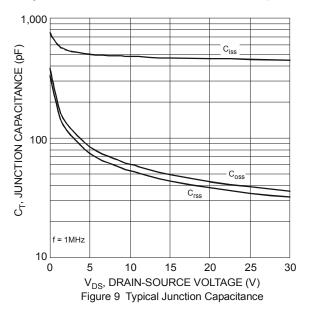
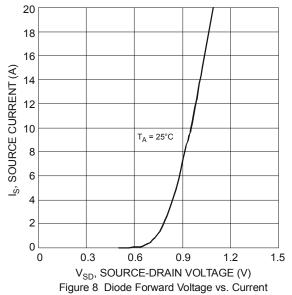
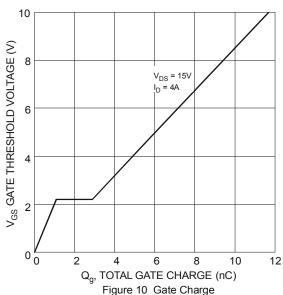


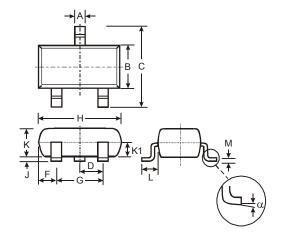
Figure 7 Gate Threshold Variation vs. Ambient Temperature







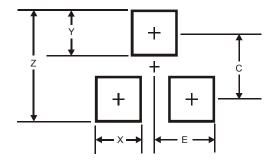
Package Outline Dimensions



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.903	1.10	1.00			
K1	-		0.400			
L	0.45	0.61	0.55			
М	0.085	0.18	0.11			
α	0°	8°	-			
All Dimensions in mm						



Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
С	2.0
E	1.35

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